

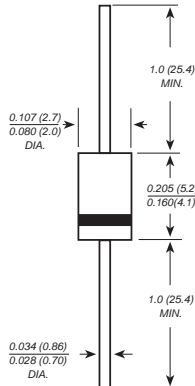


# SB120 THRU SB1200

## SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 1.0 Ampere

### DO-41



Dimensions in inches and (millimeters)

### FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:  
250°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

### MECHANICAL DATA

**Case:** JEDEC DO-41 molded plastic body  
**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026  
**Polarity:** Color band denotes cathode end  
**Mounting Position:** Any  
**Weight:** 0.012 ounce, 0.33 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	SB 120	SB 130	SB 140	SB 150	SB 160	SB 170	SB 180	SB 180	SB 190	SB 1B0	SB 1150	SB 1200	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	50	60	70	80	90	100	150	200	VOLTS	
Maximum RMS voltage	$V_{RMS}$	14	21	28	35	42	49	56	63	70	105	140	VOLTS	
Maximum DC blocking voltage	$V_{DC}$	20	30	40	50	60	70	80	90	100	150	200	VOLTS	
Maximum average forward rectified current 0.375" (9.5mm) lead length (see fig.1)	$I_{AV}$	1.0											Amp	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	40.0											Amps	
Maximum instantaneous forward voltage at 1.0A	$V_F$	0.55		0.70		0.85			0.95			Volts		
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	$I_R$	0.5					0.2			0.2			mA	
		10.0			5.0			2.0						
Typical junction capacitance (NOTE 1)	$C_J$	110			80						pF			
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0											°C/W	
Operating junction temperature range	$T_J$	-65 to +125					-65 to +150					°C		
Storage temperature range	$T_{STG}$	-65 to +150											°C	

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

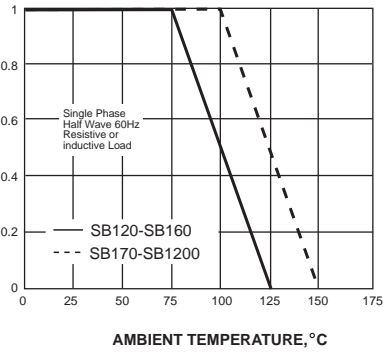


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# RATINGS AND CHARACTERISTIC CURVES SB120 THRU SB1200

AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

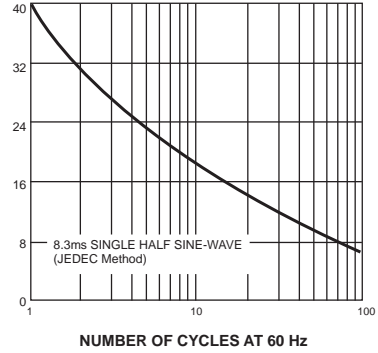


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

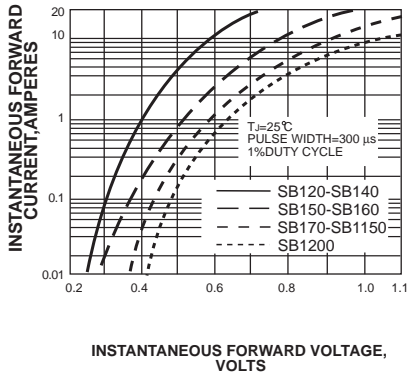


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

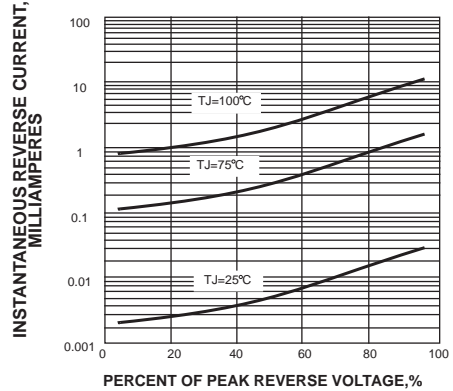
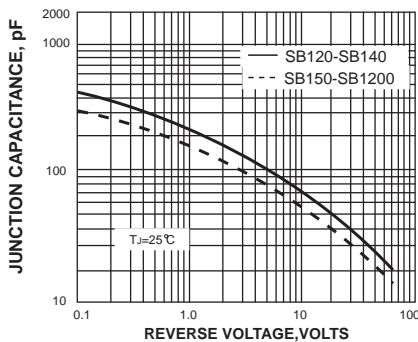
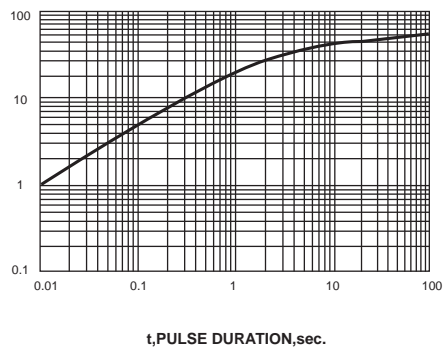


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考!)

